# NSN 5962-01-317-3178

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Between 0.357 inches and 0.432 inches

**Body Length:** 

1.490 inches

**Body Width:** 

Between 0.500 inches and 0.610 inches

**Body Height:** 

Between 0.172 inches and 0.217 inches

**Maximum Power Dissipation Rating:** 

1.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Training set, countermeasures signals an/msr-t4

#### **Features Provided:**

Hermetically sealed and burn in and static operation and low power

#### **Inclosure Material:**

Ceramic

## **Inclosure Configuration:**

Dual-in-line

#### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

## **Input Circuit Pattern:**

26 input

#### **Case Outline Source And Designator:**

D-10 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 70.0 volts power source

#### **Time Rating Per Chacteristic:**

45.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level output

#### **Memory Device Type:**

Ram

#### **Memory Capacity:**

Unknown

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

28 printed circuit

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N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

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